SGM3837B
Triple-Output 1100mA AMOLED Display Power Supply

GENERAL DESCRIPTION

The SGM3837B is designed for powering AMOLED (Active Matrix Organic LED) displays which require V_{ELVDD}, V_{ELVSS} and V_{AVDD}. The device integrates two Boost converters, VO1 for V_{ELVDD} and VO3 for V_{AVDD}, and one inverting Buck-Boost converter VO2 for V_{ELVSS}. Output voltages of all the three converters can be programmed in digital steps through the digital interface control pins (ASWIRE & ESWIRE).

The SGM3837B is available in a Green WLCSP-2.04×2.04-25B package.

FEATURES

- **2.2V to 5.0V Input Supply Voltage Range**
- **Synchronous Boost Converter (ELVDD)**
  - **4.6V to 5.0V Output Voltage with 100mV Steps**
  - **4.6V Default Output Voltage**
  - **1100mA Output Current Capability**
- **Synchronous Inverting Buck-Boost Converter (ELVSS)**
  - **-6.0V to -0.5V Output Voltage with 25mV Steps**
  - **-1.4V Default Output Voltage**
  - **1100mA Output Current Capability @ V_{ELVSS} = -5.5V, V_{IN} = 2.7V**
- **Synchronous Boost Converter (AVDD)**
  - **5.5V to 7.8V Output Voltage (SET = Low)**
  - **5.5V to 8.0V Output Voltage (SET = High)**
  - **7.6V Default Output Voltage**
  - **150mA Output Current Capability**
- **Selectable ASWIRE Setting via SET Pin**
- **V_{IN} and V_{OUT} Bi-Directional Isolation**
- **Short-Circuit Protection (SCP)**
- **Overload Protection**
- **Thermal Shutdown**
- **V_{ELVSS} Start-Up Delay: 5.7ms**
- **Short-Circuit and OLP Detection Time: 0.71ms**
- **Available in a Green WLCSP-2.04×2.04-25B Package**

APPLICATIONS

Smartphone & Tablet
Active Matrix OLED Display

TYPICAL APPLICATION

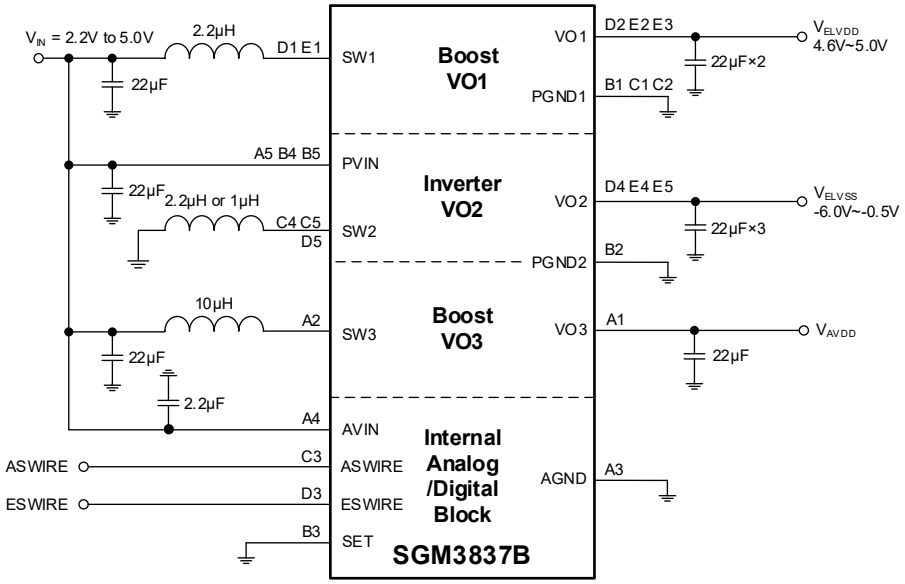


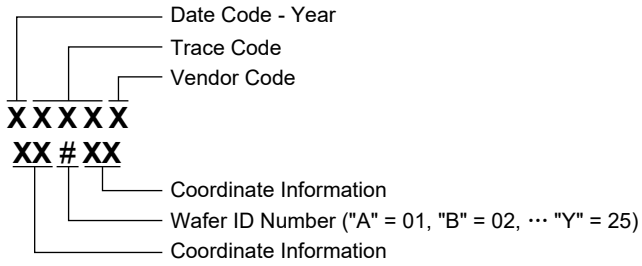
Figure 1. Typical Application Circuit

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM3837B	WLCSP-2.04×2.04-25B	-40℃ to +85℃	SGM3837BYG/TR	3837B XXXXX XX#XX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code. XX#XX = Coordinate Information and Wafer ID Number.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Voltage Range (with Respect to Ground Pin)
- AVIN, PVIN, VO1, ASWIRE, SET, ESWIRE ..... -0.3V to 6V
- SW1 ..... -0.3V to 6V
- SW1 (Transient: 10ns) ..... -1V to 8V
- VO2 ..... -7V to 0.3V
- SW3, VO3 ..... -0.3V to 9V
- SW3 (Transient: 10ns) ..... -1V to 11V
- SW2 ..... -7V to 6V
- SW2 (Transient: 10ns) ..... -9V to 8V

PGND1, PGND2 to AGND ..... -0.3V to 0.3V

Package Thermal Resistance
- WLCSP-2.04×2.04-25B, θ_{JA} ..... 49.2℃/W
- WLCSP-2.04×2.04-25B, θ_{JB} ..... 6.4℃/W
- WLCSP-2.04×2.04-25B, θ_{JC} ..... 16.3℃/W

Junction Temperature ..... +150℃

Storage Temperature Range ..... -65℃ to +150℃

Lead Temperature (Soldering, 10s) ..... +260℃

ESD Susceptibility (1) (2)

HBM ..... ±2000V

CDM ..... ±1000V

NOTES:

1. For human body model (HBM), all pins comply with ANSI/ESDA/JEDEC JS-001 specifications.

2. For charged device model (CDM), all pins comply with ANSI/ESDA/JEDEC JS-002 specifications.

RECOMMENDED OPERATING CONDITIONS

Operating Ambient Temperature Range ..... -40℃ to +85℃

Operating Junction Temperature Range ..... -40℃ to +125℃

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

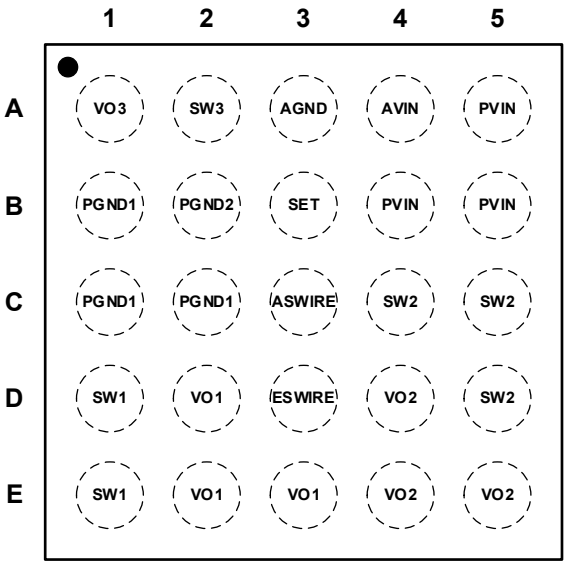
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION

(TOP VIEW)



WLCSP-2.04×2.04-25B

PIN DESCRIPTION

PIN	NAME	TYPE	DESCRIPTION
A1	VO3	O	VO3 Boost Converter Output.
B1, C1, C2	PGND1	G	VO1 Boost Converter Power Ground.
D1, E1	SW1	I/O	VO1 Boost Converter Switching Node.
A2	SW3	I/O	VO3 Boost Converter Switching Node.
B2	PGND2	G	VO2 Inverting Buck-Boost Converter and VO3 Boost Converter Power Ground.
D2, E2, E3	VO1	O	VO1 Boost Converter Output.
A3	AGND	G	Analog Ground Pin.
B3	SET	I	VO3 Output Voltage Table Setting Pin.
C3	ASWIRE	I	VO3 Boost Converter Enable Control and Programming Pin.
D3	ESWIRE	I	VO1 Boost Converter and VO2 Inverting Buck-Boost Converter Enable Control and Programming Pin.
A4	AVIN	I	Analog Input Supply Pin.
B4, A5, B5	PVIN	I	Power Input Supply Pin.
C4, C5, D5	SW2	I/O	VO2 Inverting Buck-Boost Converter Switching Node.
D4, E4, E5	VO2	O	VO2 Inverting Buck-Boost Converter Output.

NOTE: I = input, O = output, I/O = input or output, G = ground.

ELECTRICAL CHARACTERISTICS

(At T_A = T_J = +25℃, V_{AVIN} = V_{PVIN} = V_{IN} = 3.7V, V_{ESWIRE} = V_{ASWIRE} = V_{AVIN}, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Current and Thermal Protection						
AVIN, PVIN Input Voltage Range	V_{S_VIN}		2.2		5	V
AVIN Start Threshold Voltage	V_{START}	V_{AVIN} rising	1.9	2	2.1	V
AVIN Stop Threshold Voltage	V_{STOP}	V_{AVIN} falling	1.8	1.9	2	V
AVIN, PVIN Supply Current when Disabled	I_{SD_VIN}	V_{IN} = 4.5V, V_{ASWIRE} = 0V, V_{ESWIRE} = 0V (sum of I_{AVIN} and I_{PVIN})		0.6	2	μA
AVIN, PVIN Supply Current	I_Q	No switching		0.6	1.5	mA
		No load, V_{ASWIRE} = V_{ESWIRE} = high		3.5		
Thermal Shutdown Temperature	T_{SD}	Temperature rising		145		℃
		Temperature falling		135		℃
Boost Converter (V_{VO1} = V_{ELVDD})						
Positive Output 1 Voltage Range	V_{VO1}	4.6V to 5.0V with 100mV/step, default 4.6V	4.6	4.6	5.0	V
Positive Output 1 Voltage Variation		V_{VO1} = 4.6V, no load	-0.5		0.5	%
		V_{VO1} = 4.6V, no load, T_J = -40℃ to +85℃	-0.7		0.7	
SW1 Switching Frequency	f_{SW1}	I_{VO1} = 100mA	1.3	1.45	1.6	MHz
SW1 Current Limit	I_{SW1_LIM}	Inductor valley current		3.2		A
Maximum Output Current	I_{VO1_MAX}	V_{IN} = 2.7V to 5.0V	1100			mA
SW1 Low-side TR On-Resistance	R_{DSON_SW1L}	I_{SW1} = 0.2A		40		mΩ
SW1 High-side TR On-Resistance	R_{DSON_SW1H}	I_{SW1} = 0.2A		60		mΩ
VO1 Short-Circuit Protection	V_{VO1_SCP}	Percentage of normal V_{VO1}		85		%
Discharging Resistance	R_{DCHG_VO1}			30		Ω
Line Regulation (1)	$VO1_{LINEREG}$	I_{VO1} = 100mA, V_{IN} = 2.2V to 5.0V		2	10	mV
Load Regulation (1)	$VO1_{LOADREG}$	I_{VO1} = 1mA to 1100mA		14	20	mV
Output Voltage Ripple (1)	$VO1_{RIPPLE}$	I_{VO1_VO2} = 0mA to 850mA, V_{IN} = 2.5V to 5.0V		30		mV_{PP}
Line Transient (1)	$VO1_{LINETRS}$	V_{IN} = 2.5V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 600mA		72		mV_{PP}
		V_{IN} = 3.0V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 850mA		56		mV_{PP}
		V_{IN} = 3.0V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 1100mA		90		mV_{PP}
Load Transient (1)	$VO1_{LOADTRS}$	V_{IN} = 2.5V to 5.0V, t_R = t_F = 5ms, I_{VO1_VO2} = 10mA to 500mA		30		mV_{PP}
Efficiency	$Eff_{VO1-VO2}$	V_{IN} = 3.7V, V_{VO1} = 4.6V, V_{VO2} = -2V, I_{VO1_VO2} = 50mA to 300mA		94		%
Buck-Boost Converter (V_{VO2} = V_{ELVSS})						
Negative Output Voltage Range	V_{VO2}	-6.0V to -0.5V with 25mV/step, default -1.4V	-6.0	-1.4	-0.5	V
Negative Output Voltage Variation		V_{VO2} = -1.4V, no load	-30		30	mV
		V_{VO2} = -1.4V, no load, T_J = -40℃ to +85℃	-35		35	
		V_{VO2} = -4V, no load	-0.7		0.7	%
		V_{VO2} = -4V, no load, T_J = -40℃ to +85℃	-1		1	
SW2 Switching Frequency	f_{SW2}	I_{VO2} = 200mA	1.1	1.25	1.4	MHz
SW2 Current Limit	I_{SW2_LIM}	Inductor peak current		5.6		A
Maximum Output Current	I_{VO2_MAX}	V_{IN} = 2.7V to 5.0V, V_{VO2} = -5.5V	1100			mA
SW2 Low-side TR On-Resistance	R_{DSON_SW2L}	I_{SW2} = 0.2A		40		mΩ
SW2 High-side TR On-Resistance	R_{DSON_SW2H}	I_{SW2} = 0.2A		60		mΩ
VO2 Short-Circuit Protection	V_{VO2_SCP}	Percentage of normal V_{VO2}		80		%

ELECTRICAL CHARACTERISTICS (continued)

(At T_A = T_J = +25℃, V_{AVIN} = V_{PVIN} = V_{IN} = 3.7V, V_{ESWIRE} = V_{ASWIRE} = V_{AVIN}, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Discharging Resistance	R_{DCHG_VO2}			32		Ω
Line Regulation (1)	$VO2_{LINEREG}$	I_{VO2} = 100mA, V_{IN} = 2.2V to 5.0V		0.5	10	mV
Load Regulation (1)	$VO2_{LOADREG}$	I_{VO2} = 1mA to 1100mA		4	10	mV
Output Voltage Ripple (1)	$VO2_{RIPPLE}$	I_{VO1_VO2} = 0mA to 600mA, V_{VO2} = -4V, V_{IN} = 2.5V to 5.0V		25		mV_{PP}
		I_{VO1_VO2} = 0mA to 850mA, V_{VO2} = -4V, V_{IN} = 2.5V to 5.0V		30		mV_{PP}
Line Transient (1)	$VO2_{LINETRS}$	V_{IN} = 2.5V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 600mA, V_{VO2} = -4V		40		mV_{PP}
		V_{IN} = 3.0V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 850mA, V_{VO2} = -4V		44		mV_{PP}
		V_{IN} = 3.0V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO1_VO2} = 0mA to 1100mA, V_{VO2} = -4V		57		mV_{PP}
Load Transient (1)	$VO2_{LOADTRS}$	V_{IN} = 2.5V to 5.0V, t_R = t_F = 5ms, V_{VO2} = -4V, I_{VO1_VO2} = 10mA to 500mA		30		mV_{PP}
Boost Converter (V_{VO3} = V_{AVDD})						
Positive Output 3 Voltage Range	V_{VO3}	5.5V to 7.8V with 100mV/step, default 7.6V, SET = low	5.5	7.6	7.8	V
		5.5V to 8.0V with 50mV/step, default 7.6V, SET = high	5.5	7.6	8.0	V
Positive Output 3 Voltage Variation		V_{VO3} = 7.6V, no load	-0.5		0.5	%
		V_{VO3} = 7.6V, no load, T_J = -40℃ to +85℃	-0.7		0.7	
SW3 Switching Frequency	f_{SW3}	I_{VO3} = 100mA	1.3	1.45	1.6	MHz
SW3 Current Limit	I_{SW3_LIM}	Inductor peak current		1.2		A
Maximum Output Current	I_{VO3_MAX}	V_{IN} = 2.5V to 5.0V	150			mA
SW3 Low-side TR On-Resistance	R_{DSON_SW3L}	I_{SW3} = 0.1A		0.2		Ω
SW3 High-side TR On-Resistance	R_{DSON_SW3H}	I_{SW3} = 0.1A		0.5		Ω
VO3 Short-Circuit Protection	V_{VO3_SCP}	Percentage of normal V_{VO3}		85		%
Discharging Resistance	R_{DCHG_VO3}			33		Ω
Line Regulation (1)	$VO3_{LINEREG}$	I_{VO3} = 50mA, V_{IN} = 2.2V to 5.0V		0.8	10	mV
Load Regulation (1)	$VO3_{LOADREG}$	I_{VO3} = 1mA to 150mA		0.4	10	mV
Output Voltage Ripple (1)	$VO3_{RIPPLE}$	I_{VO3} = 0mA to 150mA, V_{IN} = 2.5V to 5.0V		33		mV_{PP}
Line Transient (1)	$VO3_{LINETRS}$	V_{IN} = 2.5V to 5.0V, ΔV_{IN} = 300mV, t_R = t_F = 10μs, I_{VO3} = 0mA to 120mA		65		mV_{PP}
Load Transient (1)	$VO3_{LOADTRS}$	V_{IN} = 2.5V to 5.0V, t_R = t_F = 10μs, I_{VO3} = 5mA to 35mA / 10mA to 50mA		85		mV_{PP}
Load Transient Recovery Time (1)	$VO3_{LOADREG_REC}$	V_{IN} = 2.2V to 5.0V, t_R = t_F = 10μs, I_{VO3} = 5mA to 35mA / 10mA to 50mA		50		μs
SET						
SET Input High Threshold Voltage (1)	V_{SETH}	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃	0.8			V
SET Input Low Threshold Voltage (1)	V_{SEWTL}	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃			0.4	V
Pull-Down Resistor	$R_{DOWNSET}$			37		MΩ
ESWIRE						
ESWIRE Input High Threshold Voltage	$V_{ESWIREH}$	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃	0.8			V
ESWIRE Input Low Threshold Voltage	$V_{ESWIREL}$	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃			0.4	V
Pull-Down Resistor	R_{DOWNES}			600		kΩ
Initialization Time (1) (2)	t_{INIT_E}				400	μs
Shutdown Time Period (1) (3)	t_{OFF_E}				55	μs
Data Storage/Accept Time Period (1) (4)	t_{STORE_E}				55	μs

ELECTRICAL CHARACTERISTICS (continued)

(At T_A = T_J = +25℃, V_{AVIN} = V_{PVIN} = V_{IN} = 3.7V, V_{ESWIRE} = V_{ASWIRE} = V_{AVIN}, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ASWIRE						
ASWIRE Input High Threshold Voltage	$V_{ASWIREH}$	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃	0.8			V
ASWIRE Input Low Threshold Voltage	$V_{ASWIREL}$	V_{IN} = 2.2V to 5.0V, T_J = -40℃ to +85℃			0.4	V
Pull-Down Resistor	R_{DOWNES}			600		kΩ
Initialization Time (1) (2)	t_{INIT_A}				400	μs
Shutdown Time Period (1) (3)	t_{OFF_A}				55	μs
Data Storage/Accept Time Period (1) (4)	t_{STORE_A}				55	μs

NOTES:

1. Guaranteed by design and lab test.
2. The host must pull ESWIRE/ASWIRE high for a minimum of 400μs to ensure proper power-on.
3. The host must pull ESWIRE/ASWIRE low for a minimum of 55μs to ensure proper power-off.
4. The host must keep ESWIRE/ASWIRE high for a minimum of 55μs after the pulse ends to terminate the current communication.

TIMING REQUIREMENTS

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS
Short-Circuit Timer					
VO1 Short-Circuit Detection Time in Start-Up	$t_{VO1(SCP)}$	1.92	2.11	2.37	ms
VO1 Short-Circuit Detection Time in Operation		0.64	0.71	0.79	
VO2 Short-Circuit Detection Time in Start-Up	$t_{VO2(SCP)}$	5.76	6.35	7.09	
VO2 Short-Circuit Detection Time in Operation		0.64	0.71	0.79	
VO3 Short-Circuit Detection Time in Start-Up	$t_{VO3(SCP)}$	2.14	2.6	3.29	
VO3 Short-Circuit Detection Time in Operation		0.64	0.71	0.79	
ESWIRE Interface					
Pulse High Level Time Period	t_{H_E}	2	10	20	μs
Pulse Low Level Time Period	t_{L_E}	2	10	20	
ASWIRE Interface					
Pulse High Level Time Period	t_{H_A}	2	10	20	μs
Pulse Low Level Time Period	t_{L_A}	2	10	20	
Power Sequence					
VO1 Start-Up Time	t_{SS1}	2.55	3	3.48	ms
VO2 Start-Up Time	t_{SS2}	0.63	0.7	0.78	
VO2 Start-Up Time Delay	t_{DELAY}	5.14	5.7	6.34	
VO3 Start-Up Time	t_{SS3}	1.02	1.4	1.95	
VOx Discharge Time after ASWIRE or ESWIRE Goes Low	t_{DISCHG}		3		

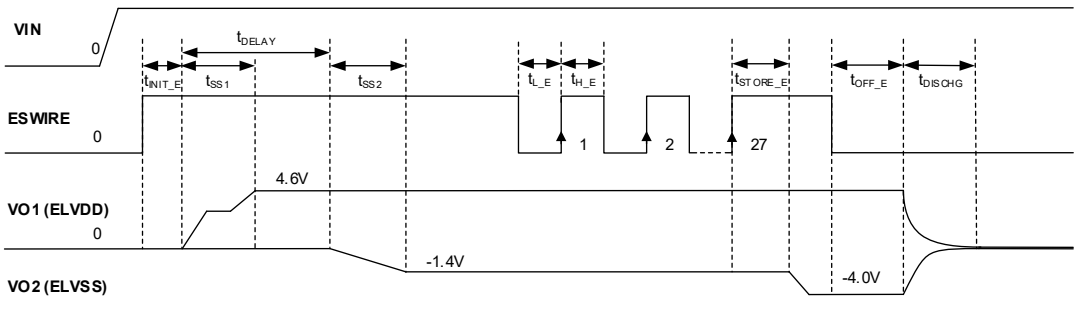


Figure 2. Timing Diagram

FUNCTIONAL BLOCK DIAGRAM

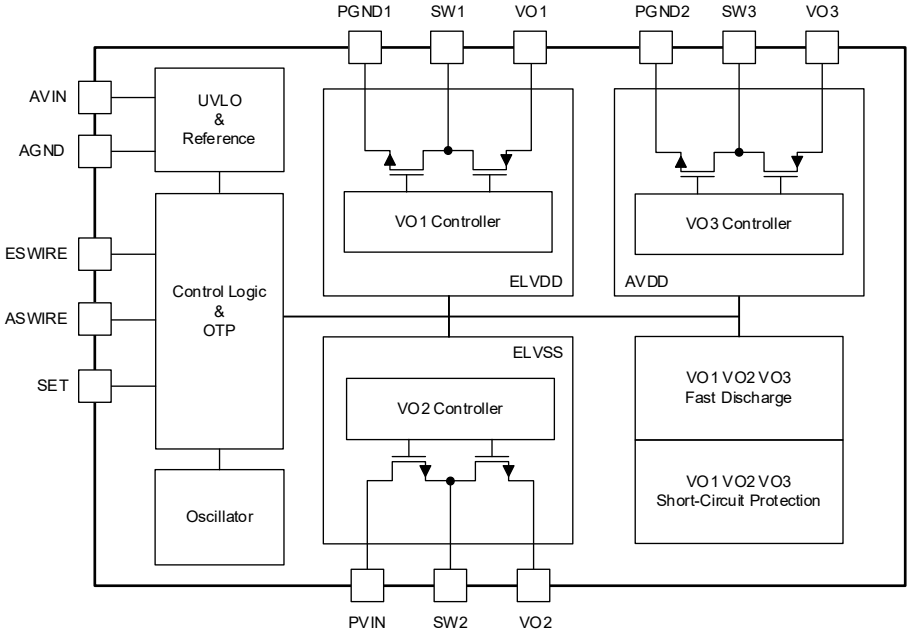


Figure 3. Functional Block Diagram

RECOMMENDED COMPONENT SELECTION

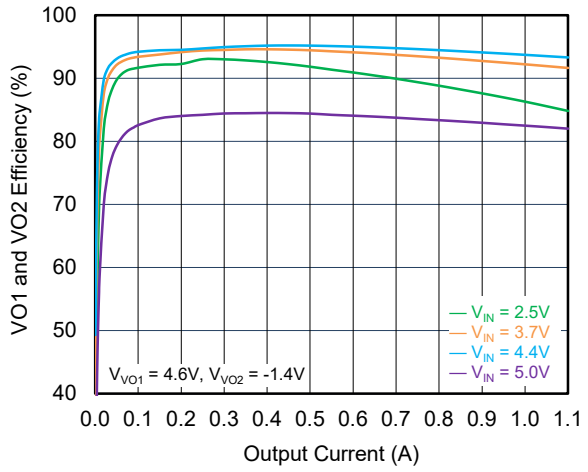
Table 1. Recommended Component Selection

Converter	Component	Value	Number	Electrical Spec	Part Number	Manufacturer
ELVDD	C_{IN1}	22μF	1	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	C_{VO1}	22μF	2	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	L_{VO1}	2.2μH	1	3.3A, 58mΩ, 201610	HTEH20161T-2R2MSR	Cyntec
ELVSS	C_{PVIN}	22μF	1	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	C_{VO2}	22μF	3	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	L_{VO2}	2.2μH	1	3.3A, 58mΩ, 201610	HTEH20161T-2R2MSR	Cyntec
		1μH	1	5.5A, 21mΩ, 252010	HTEH25201T-1R0MTR	Cyntec
AVDD	C_{IN3}	22μF	1	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	C_{VO3}	22μF	1	X5R, 10V, 0603	GRM188R61A226ME15D	Murata
	L_{VO3}	10μH	1	1.3A, 390mΩ, 252012	SDEM25201B-100MS	Cyntec
Other	C_{AVIN}	2.2μF	1	X5R, 6.3V, 0201	GRM033R60J225ME15D	Murata

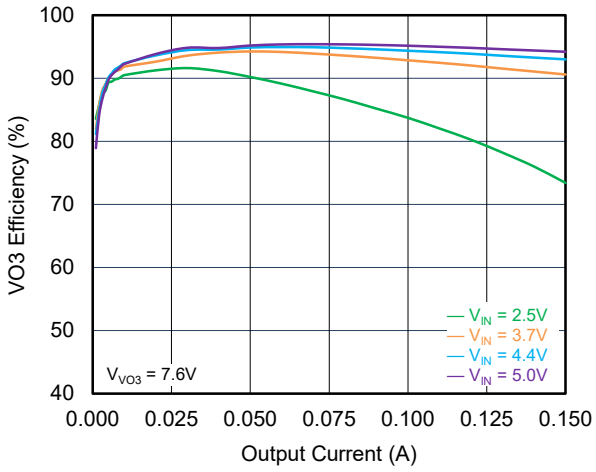
TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = 3.7V, unless otherwise noted.

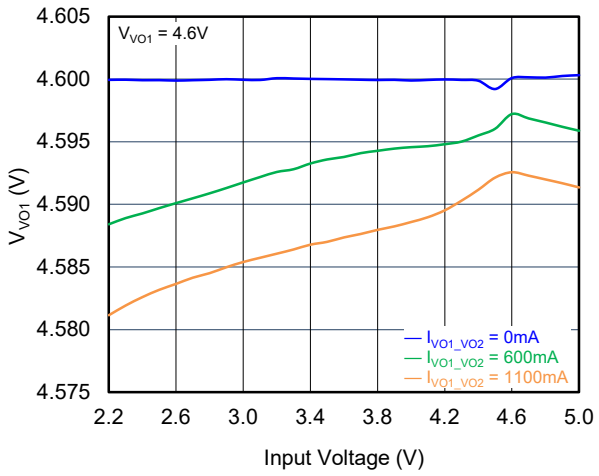
VO1 and VO2 Combined Efficiency vs. Output Current



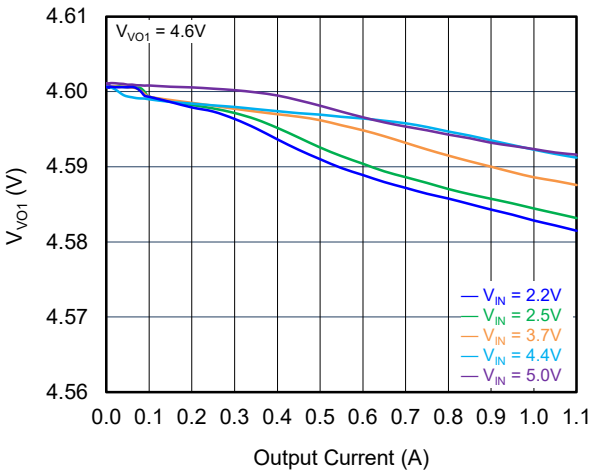
VO3 Efficiency vs. Output Current



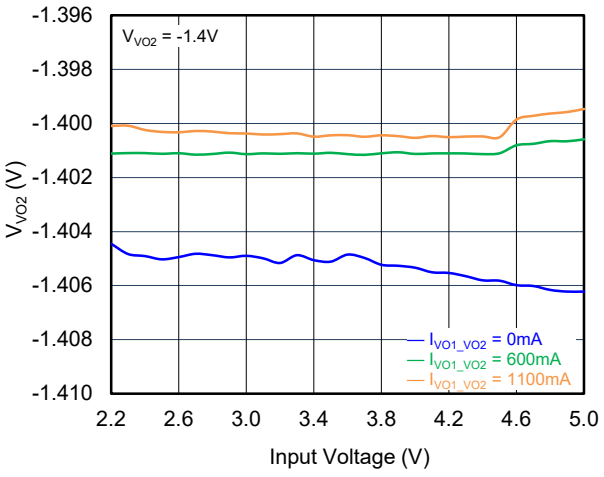
VO1 Line Regulation



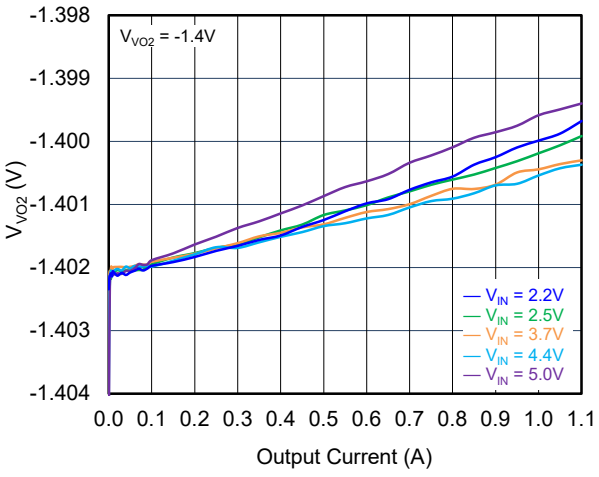
VO1 Load Regulation



VO2 Line Regulation



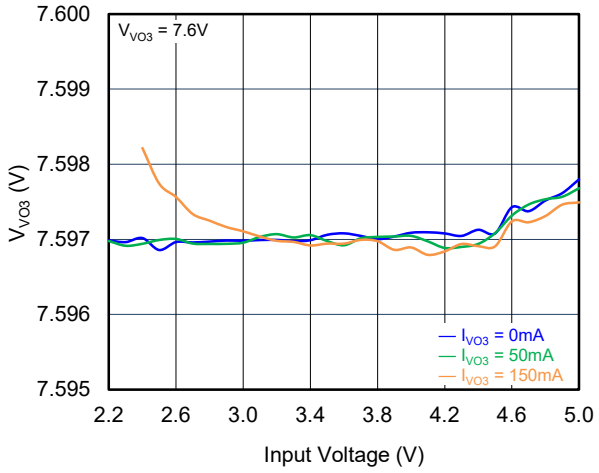
VO2 Load Regulation



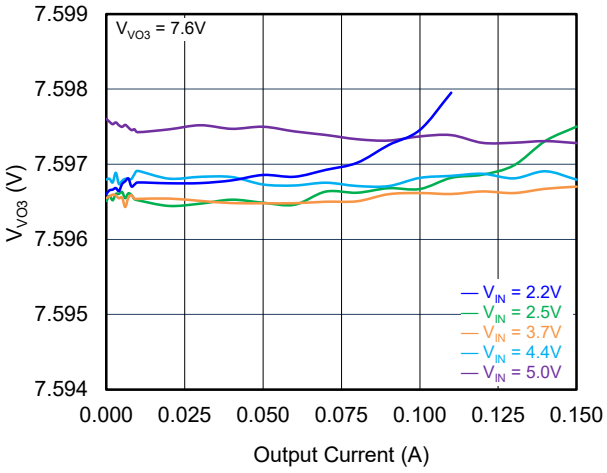
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

V_{IN} = 3.7V, unless otherwise noted.

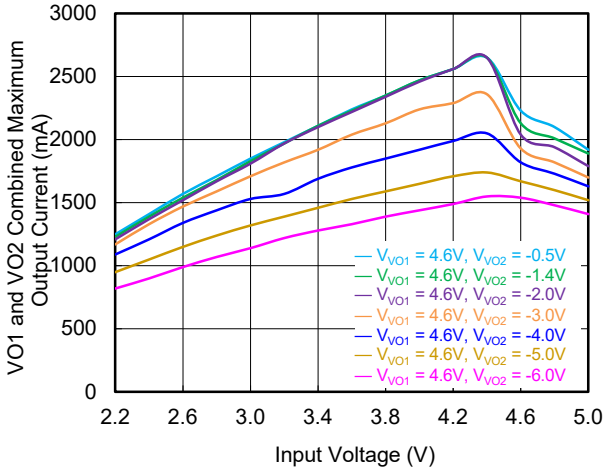
VO3 Line Regulation



VO3 Load Regulation



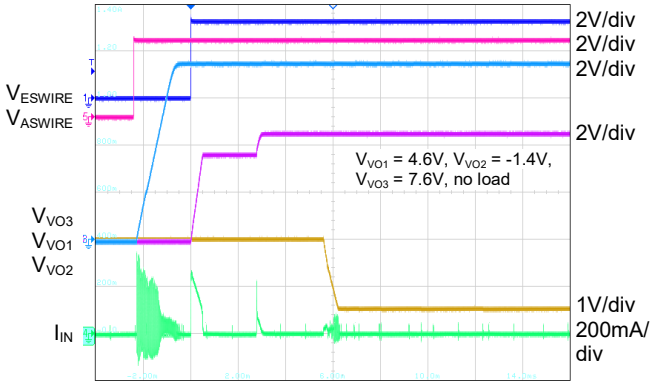
VO1 and VO2 Combined Maximum Output Current vs. Input Voltage



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

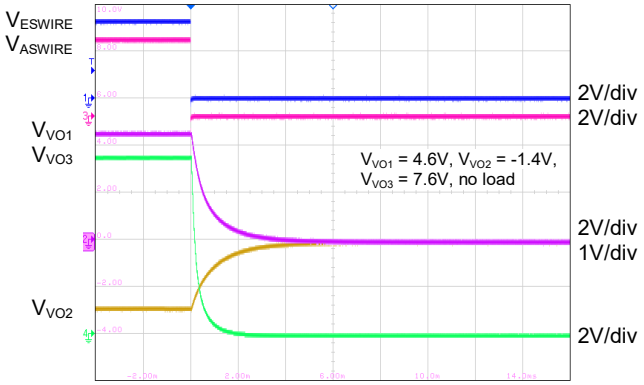
V_{IN} = 3.7V, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.

Start-Up Sequence



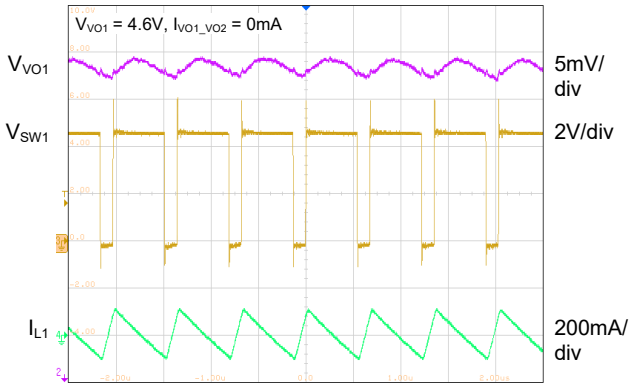
Time (2ms/div)

Shutdown Sequence Discharge = ON



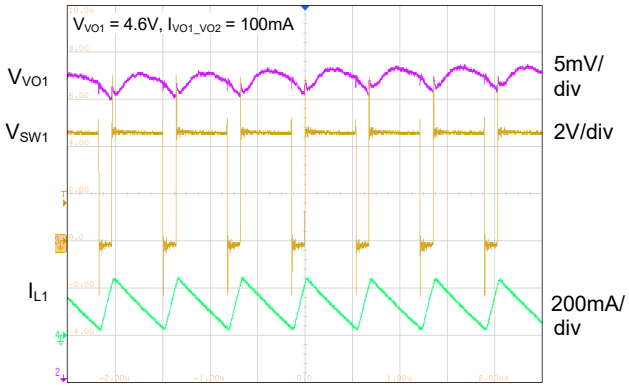
Time (2ms/div)

VO1 Output Ripple at No Load



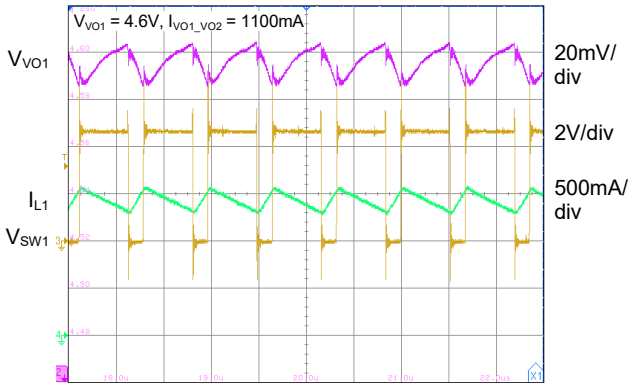
Time (500ns/div)

VO1 Output Ripple at 100mA Load



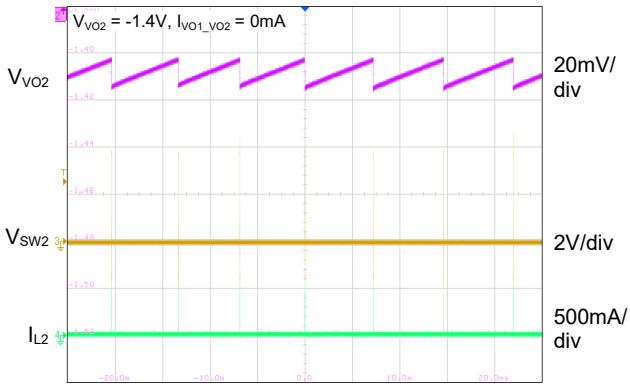
Time (500ns/div)

VO1 Output Ripple at 1100mA Load



Time (500ns/div)

VO2 Output Ripple at No Load

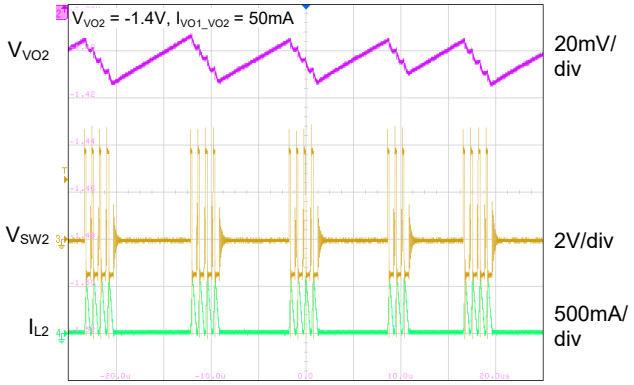


Time (5ms/div)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

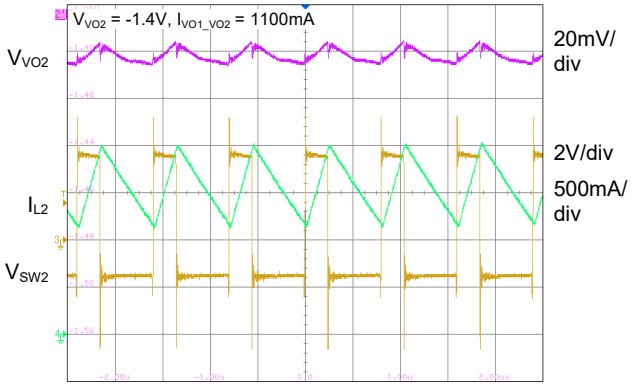
V_{IN} = 3.7V, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.

VO2 Output Ripple at 50mA Load



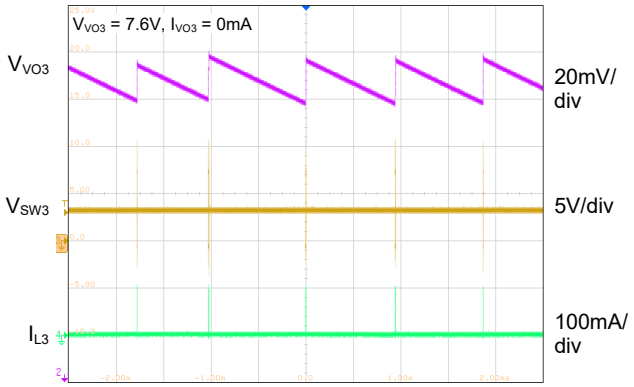
Time (5μs/div)

VO2 Output Ripple at 1100mA Load



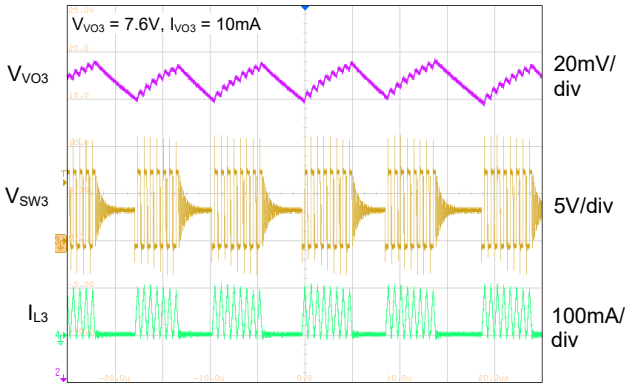
Time (500ns/div)

VO3 Output Ripple at No Load



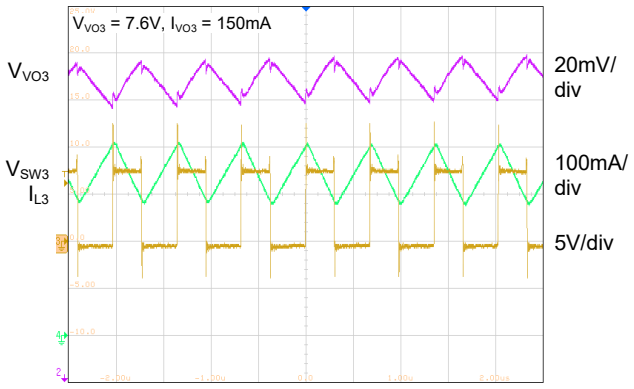
Time (500μs/div)

VO3 Output Ripple at 10mA Load



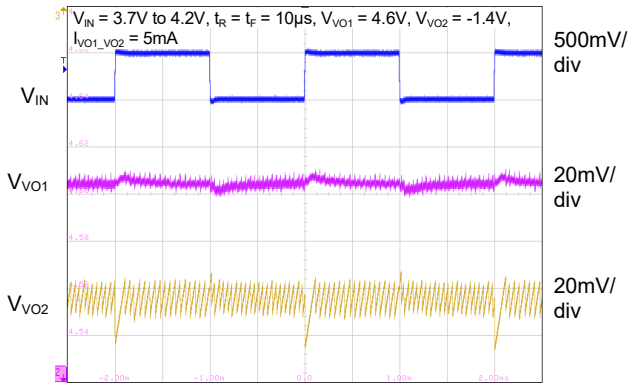
Time (5μs/div)

VO3 Output Ripple at 150mA Load



Time (500ns/div)

VO1 and VO2 Line Transient at 5mA Load

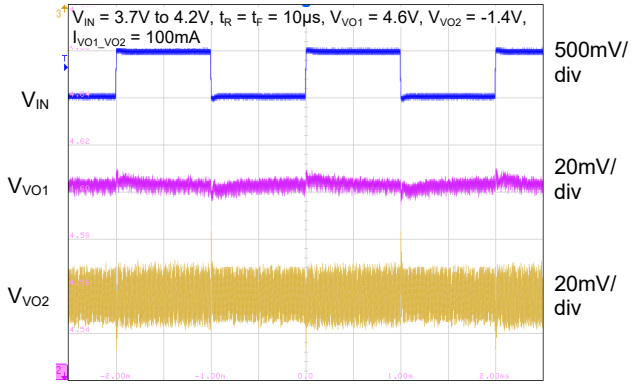


Time (500μs/div)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

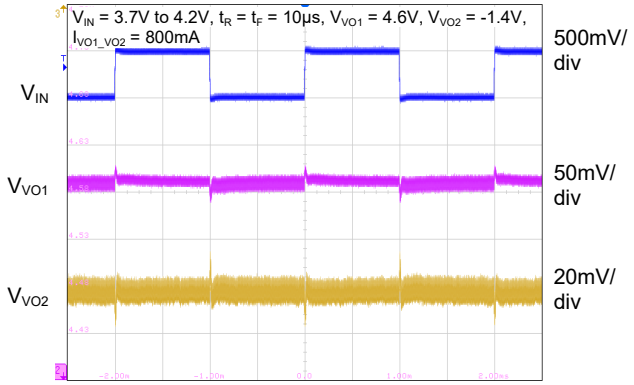
V_{IN} = 3.7V, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.

VO1 and VO2 Line Transient at 100mA Load



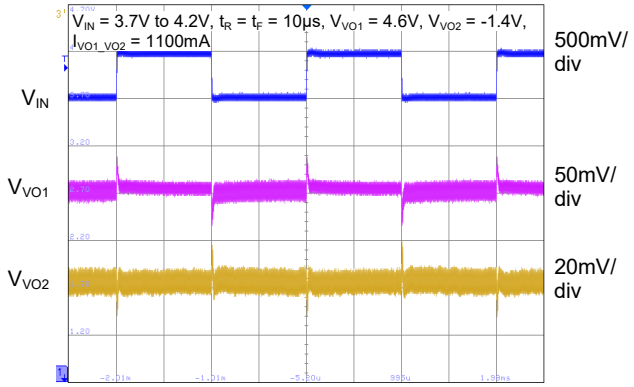
Time (500μs/div)

VO1 and VO2 Line Transient at 800mA Load



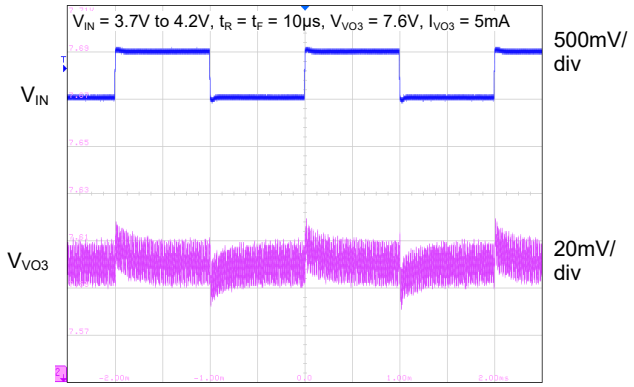
Time (500μs/div)

VO1 and VO2 Line Transient at 1100mA Load



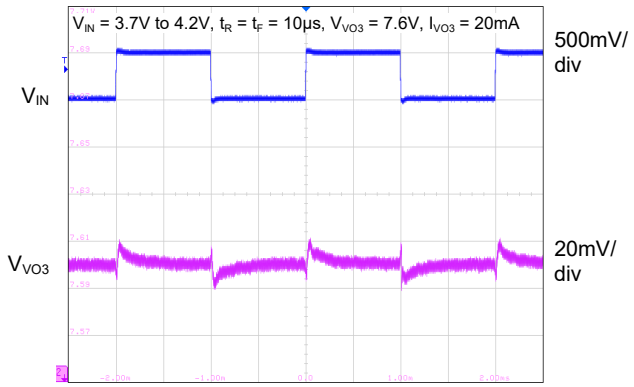
Time (500μs/div)

VO3 Line Transient at 5mA Load



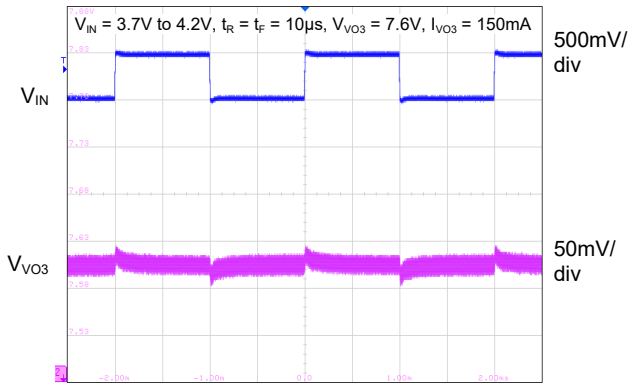
Time (500μs/div)

VO3 Line Transient at 20mA Load



Time (500μs/div)

VO3 Line Transient at 150mA Load

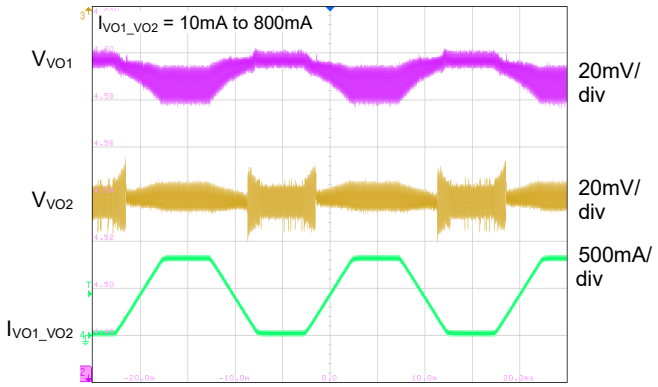


Time (500μs/div)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

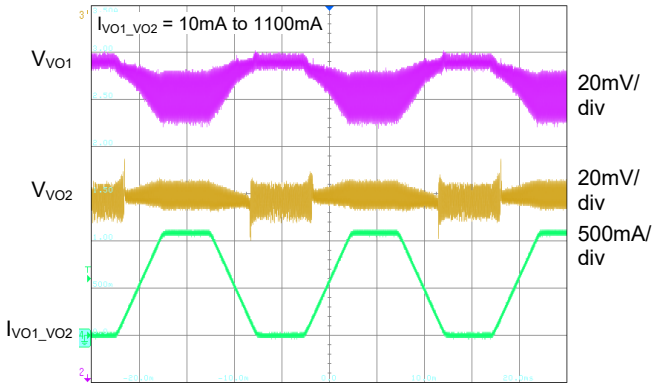
V_{IN} = 3.7V, V_{VO1} = 4.6V, V_{VO2} = -1.4V, V_{VO3} = 7.6V, unless otherwise noted.

VO1 and VO2 Load Transient



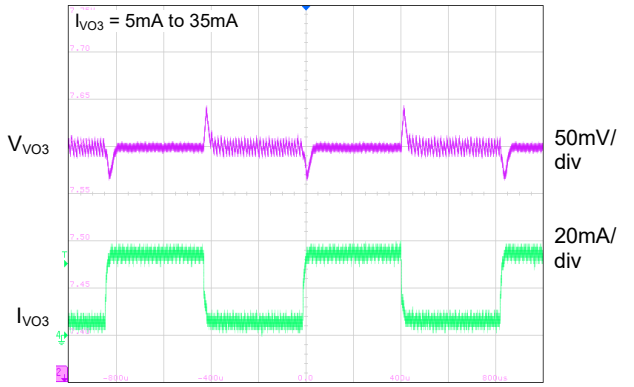
Time (5ms/div)

VO1 and VO2 Load Transient



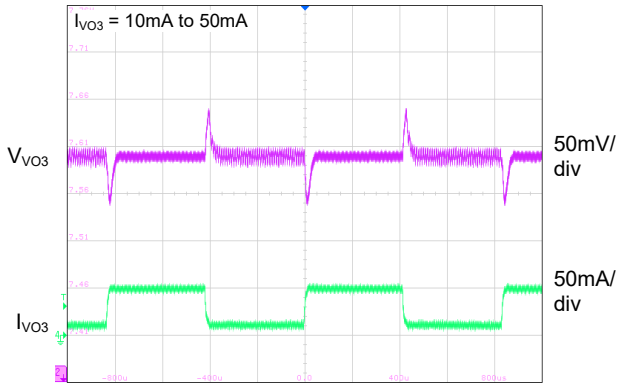
Time (5ms/div)

VO3 Load Transient



Time (200μs/div)

VO3 Load Transient



Time (200μs/div)

DETAILED DESCRIPTION

Under-Voltage Lockout (UVLO)

The built-in under-voltage lockout function (UVLO) monitors the input voltage and disables the device when the input voltage is too low to operate.

Thermal Shutdown (TSD)

The device has a function of thermal shutdown, which prevents the device from damage due to overheating and excessive power dissipation. The device shuts down all the outputs once the junction temperature exceeds +145℃ (TYP). It resumes operation when the junction temperature falls below +135℃ (TYP).

Start-Up Sequence

Pulling ASWIRE high enables the VO3 Boost converter. Pulling ESWIRE high enables the VO1 Boost converter and VO2 Buck-Boost converter. The VO2 always starts 5.7ms later than VO1 with a -1.4V default value. All converters start with soft-start function to limit the inrush current. Figure 4 shows the start-up sequence of SGM3837B.

Boost Converter VO1 (ELVDD)

The Boost converter VO1 operates with valley-current-mode topology and fixed 1.45MHz (TYP) frequency. The VO1 output voltage can be programmed between 4.6V and 5.0V (default 4.6V) with 100mV steps through ESWIRE pin (see Table 2).

The output of VO1 is fully isolated in shutdown mode.

Inverting Buck-Boost Converter VO2 (ELVSS)

The inverting Buck-Boost converter VO2 operates with a peak-current-mode topology and fixed 1.25MHz (TYP) frequency. The VO2 output voltage can be programmed between -6.0V and -0.5V (default -1.4V) with 25mV steps through ESWIRE pin (see Table 2).

The output of VO2 is fully isolated in shutdown mode.

Boost Converter VO3 (AVDD)

The Boost converter VO3 operates with a peak-current-mode topology and fixed 1.45MHz (TYP) frequency. The VO3 output voltage can be programmed through ASWIRE pin, and the output voltage table can be changed by SET pin. When SET = low, the VO3 voltage is available between 5.5V and 7.8V (default 7.6V) with 100mV steps. While SET = high, the VO3 voltage is available between 5.5V and 8.0V (default 7.6V) with 50mV steps (see Table 3).

The output of VO3 is fully isolated in shutdown mode.

Output Current Capacity

The device operates with an input voltage range of 2.2V to 5.0V. However, due to different input voltage and different output voltage, the output current capacity is quite different. A lower input voltage or a higher output voltage leads to a lower output current capacity.

Input Power Supply

The input power supply voltage is recommended between 2.2V and 5.0V. To achieve full performance, a stable and noise-free input source is needed. Once the distance between input source and SGM3837B is a bit long, additional capacitors are suggested to place as close to the device as possible. Please refer to the typical application circuit for the suggested input capacitance.

SGMICRO has patented circuits to solve the spike problem of V_{ELVDD} due to mode switching when the input voltage rises close to or higher than the programmed V_{ELVDD}.

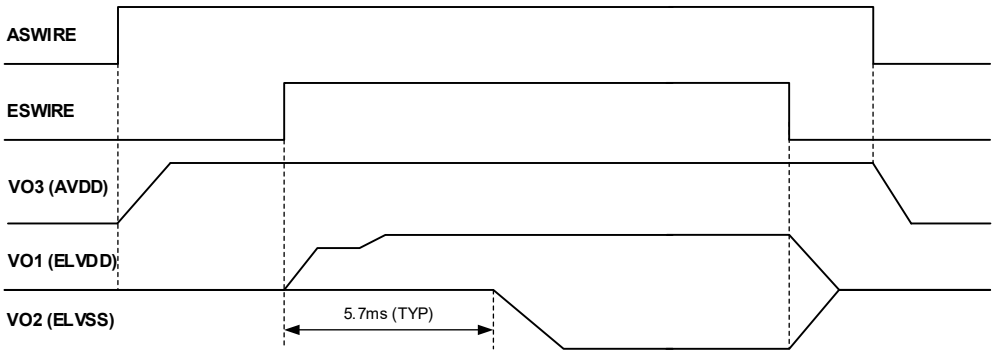


Figure 4. Start-Up Sequence

DETAILED DESCRIPTION (continued)

Table 2. Programming Table for VO1 and VO2 (ESWIRE)

ESWIRE Pulse	VO2 (ELVSS)	ESWIRE Pulse	VO2 (ELVSS)	ESWIRE Pulse	VO2 (ELVSS)	ESWIRE Pulse	VO1 (ELVDD)
0/no pulse	-1.4V	26	-4.1V	47	-2.0V	0/no pulse	4.6V
1 ~ 6	Reserved	27	-4.0V	48	-1.9V	76	5.0V
7	-6.0V	28	-3.9V	49	-1.8V	77	4.9V
8	-5.9V	29	-3.8V	50	-1.7V	78	4.8V
9	-5.8V	30	-3.7V	51	-1.6V	79	4.7V
10	-5.7V	31	-3.6V	52	-1.5V	80	4.6V
11	-5.6V	32	-3.5V	53	-1.4V	81	Reserved
12	-5.5V	33	-3.4V	54	-1.3V	82	Reserved
13	-5.4V	34	-3.3V	55	-1.2V	83	ELVDD 4.7μH (default)
14	-5.3V	35	-3.2V	56	-1.1V	84	ELVDD 2.2μH
15	-5.2V	36	-3.1V	57	-1.0V	85	ELVSS 2.2μH (default)
16	-5.1V	37	-3.0V	58	-0.9V	86	ELVSS 1μH
17	-5.0V	38	-2.9V	59	-0.8V		
18	-4.9V	39	-2.8V	60	-0.7V		
19	-4.8V	40	-2.7V	61	-0.6V		
20	-4.7V	41	-2.6V	62	-0.5V		
21	-4.6V	42	-2.5V	63 ~ 66	Reserved		
22	-4.5V	43	-2.4V	67	+25mV		
23	-4.4V	44	-2.3V	68	-25mV		
24	-4.3V	45	-2.2V	69 ~ 70	Reserved		
25	-4.2V	46	-2.1V				

DETAILED DESCRIPTION (continued)

Table 3. Programming Table for VO3 and Other Functions (ASWIRE)

SET = High						SET = Low			
ASWIRE Pulse	**AVDD**	**ASWIRE Pulse**	**AVDD**	**ASWIRE Pulse**	**SSD Function**	**ASWIRE Pulse**	**AVDD**	**ASWIRE Pulse**	**SSD Function**
0/no pulse	7.60V	43	6.70V	0/no pulse	SSD Off	0/no pulse	7.60V	0/no pulse	SSD Off
1	7.90V	44	6.65V	22	SSD Off	1	7.80V	9	SSD Off
2	7.85V	45	6.60V	23	SSD On	2	7.70V	10	SSD On
3	7.80V	46	6.55V	24	-	3	7.60V	-	-
4	7.75V	47	6.50V	**ASWIRE Pulse**	**Fast Discharge**	4	7.50V	**ASWIRE Pulse**	**Fast Discharge**
5	7.70V	48	6.45V	0/no pulse	FD Off	5	7.40V	0/no pulse	FD Off
6	7.65V	49	6.40V	25	FD On	6	7.30V	11	FD On
7	7.60V	50	6.35V	26	FD Off	7	7.20V	12	FD Off
8	7.55V	51	6.30V	**ASWIRE Pulse**	**ELVSS SS Step**	8	7.10V	**ASWIRE Pulse**	**ELVSS SS Step**
9	7.50V	52	6.25V	0/no pulse	50μs/step	-	-	0/no pulse	50μs/step
10	7.45V	53	6.20V	27	150μs/step	**ASWIRE Pulse**	**AVDD**	13	150μs/step
11	7.40V	54	6.15V	28	300μs/step	29	7.00V	14	300μs/step
12	7.35V	55	6.10V	**ASWIRE Pulse**	**ELVSS Min Frequency**	30	6.90V	**ASWIRE Pulse**	**ELVSS Min Frequency**
13	7.30V	56	6.05V	0/no pulse	No Limit	31	6.80V	0/no pulse	No Limit
14	7.25V	57	6.00V	29	No Limit	32	6.70V	15	No Limit
15	7.20V	58	5.95V	30	2kHz	33	6.60V	16	2kHz
16	7.15V	59	5.90V	31	5kHz	34	6.50V	17	5kHz
17	7.10V	60	5.85V	**ASWIRE Pulse**	**ELVSS Frequency**	35	6.40V	**ASWIRE Pulse**	**ELVSS Frequency**
18	7.05V	61	5.80V	0/no pulse	1.25MHz	36	6.30V	0/no pulse	1.25MHz
19	7.00V	62	5.75V	32	1.0MHz	37	6.20V	18	1.0MHz
20	6.95V	63	5.70V	33	0.8MHz	38	6.10V	19	0.8MHz
21	6.90V	64	5.65V	**ASWIRE Pulse**	**AVDD OC**	39	6.00V	**ASWIRE Pulse**	**AVDD OC**
-	-	65	5.60V	0/73 pulse	150mA	40	5.90V	0/45 pulse	150mA
ASWIRE Pulse	**AVDD**	66	5.55V	74	80mA	41	5.80V	46	80mA
40	6.85V	67	5.50V			42	5.70V		
41	6.80V	68	8.00V			43	5.60V		
42	6.75V	69	7.95V			44	5.50V		

DETAILED DESCRIPTION (continued)

ASWIRE Interface (ASWIRE Pin)

The SGM3837B provides an ASWIRE pin to enable/disable the VO3, and program the VO3 output voltage. Figure 5 shows the timing.

After toggling ASWIRE high, the VO3 Boost converter starts with a 7.6V default voltage. The output voltage of VO3 can also be programmed through the ASWIRE interface. The programming table is illustrated in Table 3.

Fast Discharge (FD)

The SGM3837B supports fast discharge which is controlled by ASWIRE and SET pins. When power off and the FD is on state, all outputs of the device are discharged to GND. While the FD is off state, all outputs remain Hi-Z status. Table 3 shows the demands of the FD function.

ESWIRE Interface (ESWIRE Pin)

The positive output voltage V_{ELVDD} and the negative output voltage V_{ELVSS} can be programmed through the ESWIRE digital interface with 100mV steps. Moreover, V_{ELVSS} can be fine-tuned in 25mV steps through 67/68 ESWIRE pulses.

Figure 6 shows an example for SGM3837B programming V_{ELVSS} to -4.0V. The ESWIRE pin can be used as an enable pin if programming is not required. The device starts with the default values if enabled. The ESWIRE interface counts the rising edges to set the corresponding values. The device utilizes a volatile memory to store the settings. See Table 2 for more details.

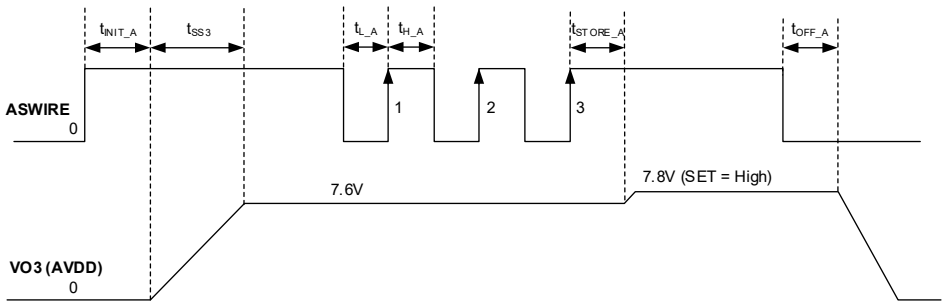


Figure 5. Timing of a Command Processing with the ASWIRE Interface

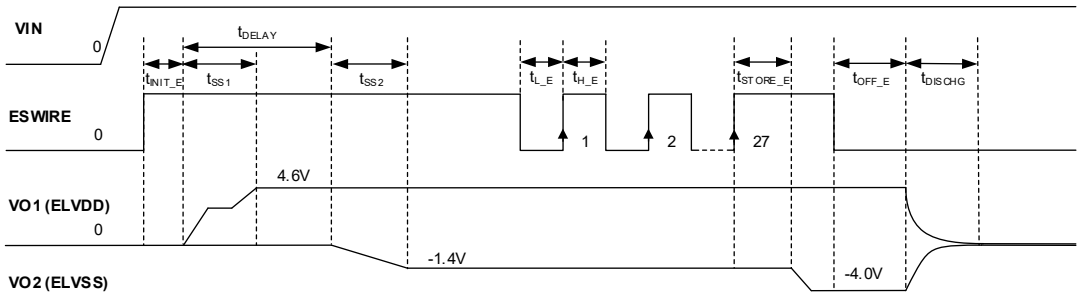


Figure 6. Timing of a Command Processing with the ESWIRE Interface

DETAILED DESCRIPTION (continued)

Soft-Start, Discharge and Start-Up Sequence

The built-in soft-start function is adopted to limit the inrush current. The output discharge function can be controlled by both SET pin and ASWIRE interface.

Toggling ESWIRE high or with relevant pulses enables the VO1 Boost converter. VO1 starts with a 0.35A soft-start current limit until it rises to the programmed voltage. Then the full current limit is active (3.2A, TYP).

5.7ms after toggling ESWIRE high, the VO2 converter starts with a -1.4V default voltage. Before VO2 rises to the default voltage it rises linearly for 0.7ms. Then the full current limit is active (5.6A, TYP).

Toggling ASWIRE high starts the VO3 Boost converter. Before VO3 rises to the default value (7.6V), it rises linearly for 1.4ms. Then the full current limit is active (1.2A, TYP).

Overload and Short-Circuit Protection (SCP)

The built-in short-circuit protection (SCP) prevents the device from damage. If any of the three outputs (VO1, VO2 and VO3) is shorted to the ground or VO1 and VO2 are shorted together, the SGM3837B will trigger the function.

When a short or an overload occurs, all the three converters stop switching, the outputs are shut down and latched.

Only resetting the power supply or pulling ASWIRE and ESWIRE low at the same time for more than t_{OFF_A} and t_{OFF_E} respectively can restart the device.

An SCP or overload occurs if any of the following events happens:

- V_{ELVDD} is not in regulation 2.11ms after V_{ELVDD} is enabled (ESWIRE = high for longer than 2.11ms) then all converters shut down.

- V_{ELVSS} is not in regulation 6.35ms after V_{ELVSS} is enabled (ELVSS starts up for longer than 6.35ms) then ELVDD and ELVSS converters shut down.

- V_{AVDD} protection is enabled when the soft-start is completed.

- V_{ELVDD} falls below 85% of the programmed output voltage longer than 0.71ms then all converters shut down.

- V_{ELVSS} rises above 80% of the programmed output voltage longer than 0.71ms then all converters shut down.

- V_{AVDD} falls below 85% of the programmed output voltage longer than 0.71ms then all converters shut down.

Device Reset

- Power resetting resets the device to default settings.

- Short-circuit and overload protection reset all settings.

- Pulling ASWIRE high to enable the V_{AVDD} converter resets the output discharge.

- Pulling ASWIRE low for t_{OFF_A} then V_{AVDD} is reset to default value of 7.6V.

- Pulling ESWIRE low for t_{OFF_E} then V_{ELVDD} and V_{ELVSS} are reset to default values of 4.6V and -1.4V respectively.

- Pulling ASWIRE and ESWIRE low at the same time for t_{OFF_A} and t_{OFF_E} respectively then all other settings and protections are reset.

DETAILED DESCRIPTION (continued)

Layout Guideline

AMOLED displays are sensitive to quality of power supplies. A good PCB layout is quite important to reduce the ripple and to enhance the line and load transients, as well as to achieve better noise, better EMI and loop stability. The recommended layout is illustrated in Figure 7.

It is recommended to follow the below PCB layout guidelines:

1. A common ground plane between analog ground (AGND) and power ground (PGNDx) to minimize ground shifts is recommended.

2. Traces of switching nodes (SW1, SW2 and SW3) should be short and wide.

3. Place input capacitors on PVIN and output capacitors on VO2 as close as possible to the device.

4. Place an independent input capacitor on AVIN as close as possible to the device.

5. Place the output capacitors on VO1 and VO3 as close as possible to the device.

6. Use short and wide traces to connect the input capacitors on PVIN and the output capacitors.

7. It is recommended to use parallel capacitors to get lower ESR.

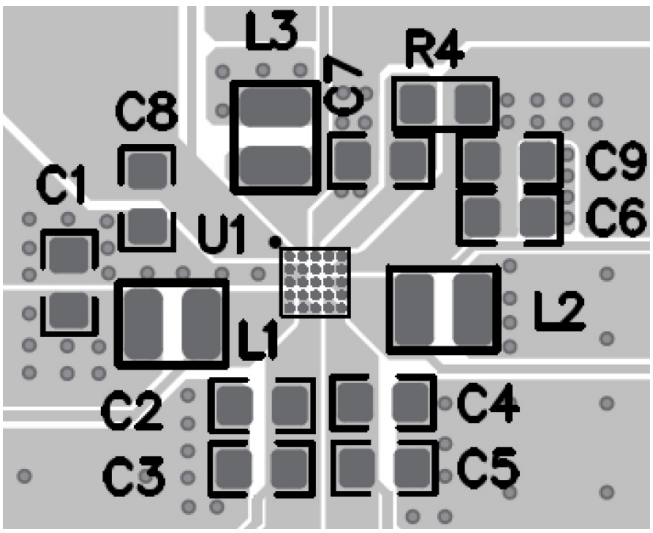


Figure 7. PCB Layout Reference

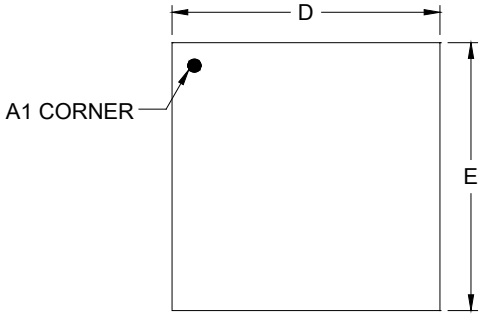
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

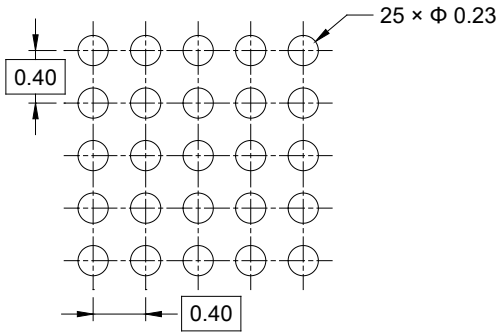
Changes from Original to REV.A (OCTOBER 2026)	Page
Changed from product preview to production data	All

PACKAGE OUTLINE DIMENSIONS

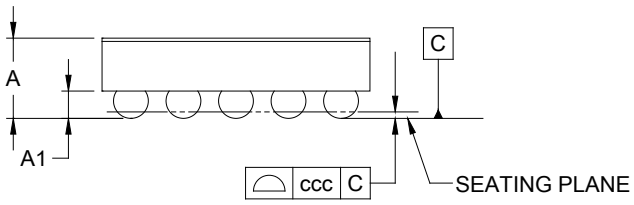
WLCSP-2.04×2.04-25B



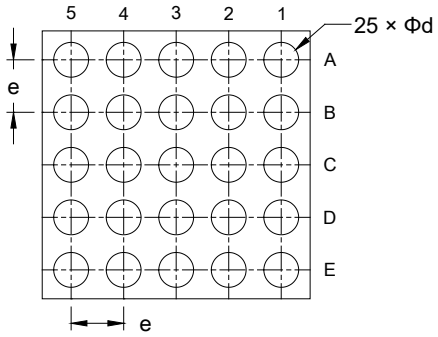
TOP VIEW



RECOMMENDED LAND PATTERN (Unit: mm)



SIDE VIEW



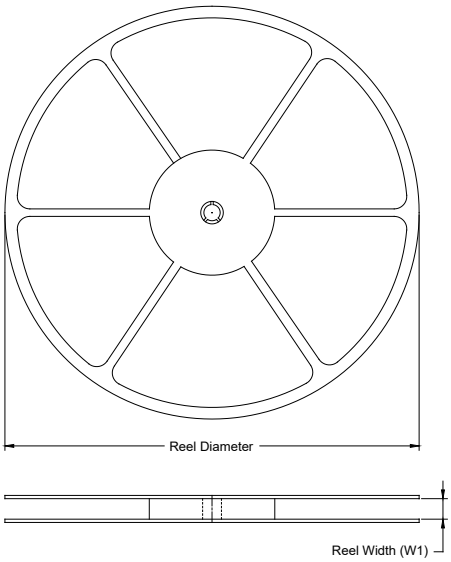
BOTTOM VIEW

Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	-	-	0.648
A1	0.188	-	0.228
D	2.010	-	2.070
E	2.010	-	2.070
d	0.235	-	0.295
e	0.400 BSC		
ccc	0.050		

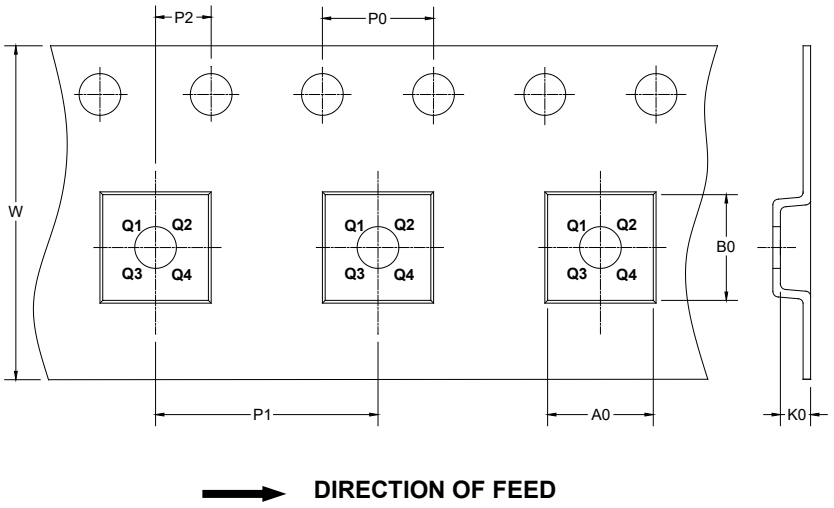
NOTE: This drawing is subject to change without notice.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



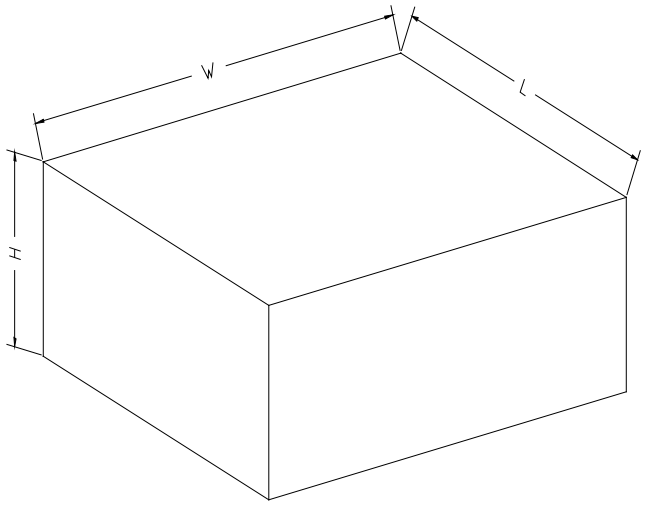
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
WLCSP-2.04×2.04-25B	7"	9.5	2.25	2.25	0.80	4.0	4.0	2.0	8.0	Q1

DD0001

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7″ (Option)	368	227	224	8
7″	442	410	224	18

DD0002